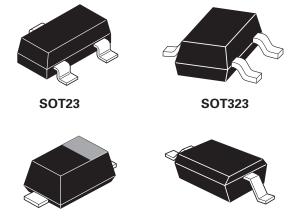


830 series Silicon 25V hyperabrupt varactor diodes

ZC829, ZDC833, ZMV829, ZMDC830 and ZV831

Description

A range of silicon varactor diodes for use in frequency control and filtering. Featuring closely controlled CV characteristics and high Q. Low reverse current ensures very low phase noise performance. Available in single or dual common cathode format in a wide rage of miniature surface mount packages.



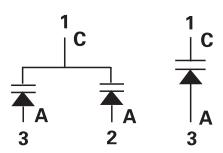
SOD523

Features

- Close tolerance CV characteristics
- · High tuning ratio
- Low I_R (typically 200pA)
- · Excellent phase noise performance
- High Q
- · Range of miniature surface mount packages

Applications

- VCXO and TCXO
- · Wireless communications
- Pagers
- · Mobile radio

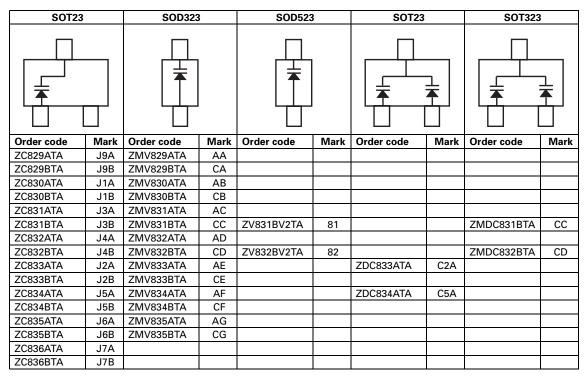


SOD323

Where steeper CV slopes are required there is the 12V hyperabrupt range:

ZC930, ZMV930, ZV930 and ZV931

Order codes and device marking



Note:

The order codes are shown as TA which is for 7 inch reels. For 13 inch reels substitute TC in place of TA in the order code.

Tape and reel information

| Reel code | Reel size (inches) | Tape width (millimeters) | Quantity per reel |
|-----------|-----------------------|--------------------------|-------------------|
| TA | 7 | 8 | 3,000 |
| TC | 13 | 8 | 10,000 |

Tuning characteristics at $T_{amb} = 25^{\circ}C$

| Part | Capacitance (pF) V _R =2V, f=1MHz | | | Min Q V _R = 3V f = 50MHz | C ₂ / | nce ratio C ₂₀ 1MHz |
|------|--|-------|-------|---|------------------|--------------------------------------|
| | Min. | Nom. | Max. | | Min. | Max. |
| 829A | 7.38 | 8.2 | 9.02 | 250 | 4.3 | 5.8 |
| 829B | 7.79 | 8.2 | 8.61 | 250 | 4.3 | 5.8 |
| 830A | 9.0 | 10.0 | 11.0 | 300 | 4.5 | 6.0 |
| 830B | 9.5 | 10.0 | 10.5 | 300 | 4.5 | 6.0 |
| 831A | 13.5 | 15.0 | 16.5 | 300 | 4.5 | 6.0 |
| 831B | 14.25 | 15.0 | 15.75 | 300 | 4.5 | 6.0 |
| 832A | 19.8 | 22.0 | 24.2 | 200 | 5.0 | 6.5 |
| 832B | 20.9 | 22.0 | 23.1 | 200 | 5.0 | 6.5 |
| 833A | 29.7 | 33.0 | 36.3 | 200 | 5.0 | 6.5 |
| 833B | 31.35 | 33.0 | 34.65 | 200 | 5.0 | 6.5 |
| 834A | 42.3 | 47.0 | 51.7 | 200 | 5.0 | 6.5 |
| 834B | 44.65 | 47.0 | 49.35 | 200 | 5.0 | 6.5 |
| 835A | 61.2 | 68.0 | 74.8 | 100 | 5.0 | 6.5 |
| 835B | 64.6 | 68.0 | 71.4 | 100 | 5.0 | 6.5 |
| 836A | 90.0 | 100.0 | 110.0 | 100 | 5.0 | 6.5 |
| 836B | 95.0 | 100.0 | 105.0 | 100 | 5.0 | 6.5 |

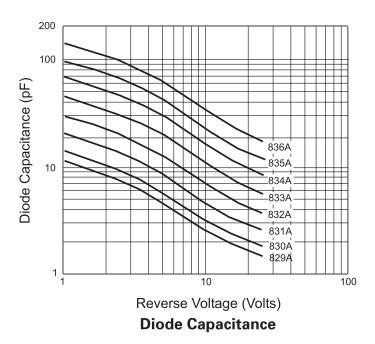
Absolute maximum ratings

| Parameter | Symbol | Max. | Unit |
|---|------------------|-------------|------|
| Forward current | I _F | 200 | mA |
| Power dissipation at T _{amb} = 25°C SOT23 | P _{tot} | 330 | mW |
| Power dissipation at T _{amb} = 25°C SOD323 | P _{tot} | 330 | mW |
| Power dissipation at T _{amb} = 25°C SOD523 | P _{tot} | 250 | mW |
| Operating and storage temperature range | | -55 to +150 | °C |

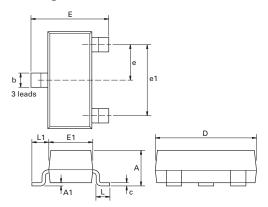
Electrical characteristics at $T_{amb} = 25^{\circ}C$

| Paramater | Conditions | Min. | Тур. | Max. | Unit |
|--|-------------------------------|------|------|------|---------|
| Reverse breakdown voltage | I _R = 10μA | 25 | | | V |
| Reverse voltage leakage | V _R = 20V | | 0.2 | 20 | nA |
| Temperature coefficient of capacitance | V _R = 3V, f = 1MHz | | 300 | 400 | ppCm/°C |

Typical characteristics



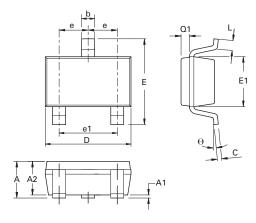
Package outline - SOT23



| Dim. | Millim | neters | Inc | hes | Dim. | Millim | eters | Inc | hes |
|------|--------|--------|--------|--------|------|--------|-------|--------|--------|
| | Min. | Max. | Min. | Max. | | Min. | Max. | Max. | Max. |
| Α | 2.67 | 3.05 | 0.105 | 0.120 | Н | 0.33 | 0.51 | 0.013 | 0.020 |
| В | 1.20 | 1.40 | 0.047 | 0.055 | K | 0.01 | 0.10 | 0.0004 | 0.004 |
| С | - | 1.10 | - | 0.043 | L | 2.10 | 2.50 | 0.083 | 0.0985 |
| D | 0.37 | 0.53 | 0.015 | 0.021 | М | 0.45 | 0.64 | 0.018 | 0.025 |
| F | 0.085 | 0.15 | 0.0034 | 0.0059 | N | 0.95 N | OM | 0.0375 | NOM |
| G | 1.90 [| MOV | 0.075 | NOM | - | - | - | - | - |

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

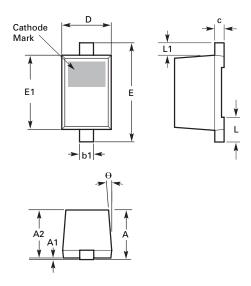
Package outline - SOT323



| Dim. | Millin | neters | Inc | hes | Dim. | Millimeters | | Inches | |
|------|--------|--------|--------|--------|------|-------------|------|------------|--------|
| | Min. | Max. | Min. | Max. | | Min. | Max. | Max. | Max. |
| Α | 0.80 | 1.10 | 0.0315 | 0.0433 | E1 | 1.15 | 1.35 | 0.0453 | 0.0532 |
| A1 | 0 | 0.10 | 0 | 0.0039 | е | 0.65 BSC | | 0.0256 BSC | |
| A2 | 0.80 | 1.00 | 0.0315 | 0.394 | e1 | 1.30 E | 3SC | 0.0512 | 2 BSC |
| b | 0.25 | 0.40 | 0.0098 | 0.0158 | L | 0.10 | 0.30 | 0.0039 | 0.0118 |
| С | 0.10 | 0.26 | 0.0039 | 0.0102 | Q1 | 0.10 | 0.40 | 0.0039 | 0.0158 |
| D | 1.80 | 2.20 | 0.0709 | 0.0866 | θ | 0° | 30° | 0° | 30° |
| Е | 1.80 | 2.40 | 0.0709 | 0.0945 | - | - | - | - | - |

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

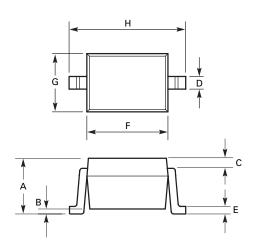
Package outline - SOD523



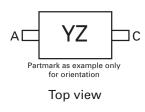
| DIM | Millin | neters | Inc | hes | DIM | Millimeters | | Inches | |
|-----|--------|--------|--------|--------|-----|-------------|-------|--------|--------|
| | Min. | Max. | Min. | Max. | | Min. | Max. | Min. | Max. |
| Α | _ | 0.800 | - | 0.0314 | Е | 1.500 | 1.700 | 0.0590 | 0.0669 |
| A1 | 0.000 | 0.100 | 0.000 | 0.0039 | E1 | 1.100 | 1.300 | 0.0433 | 0.0511 |
| A2 | 0.600 | 0.800 | 0.0236 | 0.0314 | L | 0.200 | 0.400 | 0.0078 | 0.0157 |
| b1 | 0.160 | 0.300 | 0.0062 | 0.0118 | L1 | 0.170 | 0.230 | 0.0066 | 0.0090 |
| С | 0.080 | 0.220 | 0.0031 | 0.0086 | U | 4° | 10° | 4° | 10° |
| D | 0.700 | 0.900 | 0.0275 | 0.0354 | - | - | - | - | - |

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

Package outline - SOD323



Top mark



| DIM | Millimeters | | DIM | Millin | neters |
|-----|-------------|------|-----|--------|--------|
| | Min. | Max. | | Min. | Max. |
| Α | 0.91 | 1.16 | Е | 0.127 | 0.200 |
| В | 0.00 | 0.10 | F | 1.52 | 1.77 |
| С | - | - | G | 1.11 | 1.37 |
| D | 0.33 | 0.40 | Н | 2.46 | 2.71 |

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| Product status key: | | | | |
|-----------------------------|---|--|--|--|
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| "Active" | Product status recommended for new designs | | | |
| "Last time buy (LTB)" | Device will be discontinued and last time buy period and delivery is in effect | | | |
| "Not recommended for new de | esigns" Device is still in production to support existing designs and production | | | |
| "Obsolete" | Production has been discontinued | | | |
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